

**DESCRIPTION**

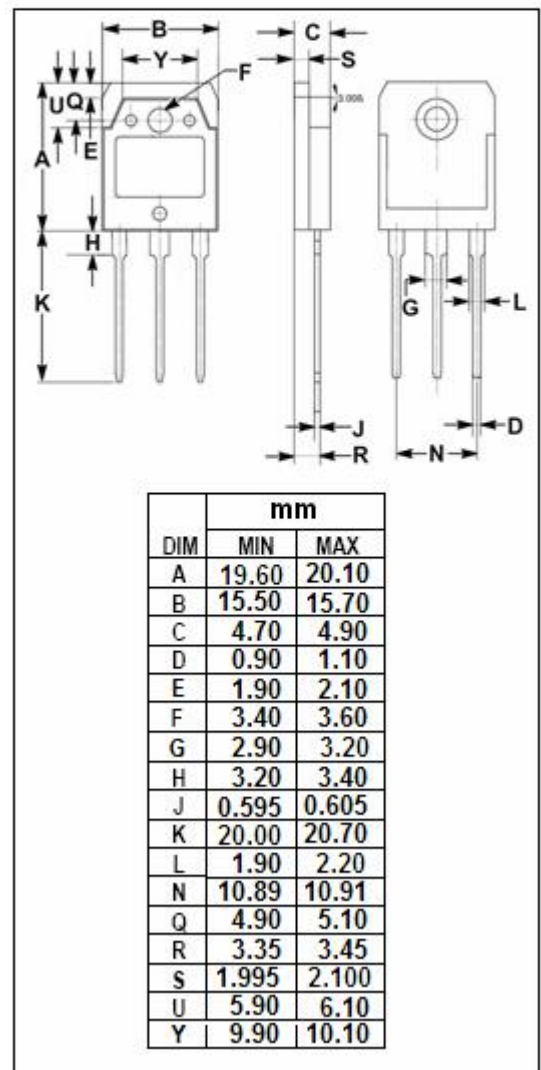
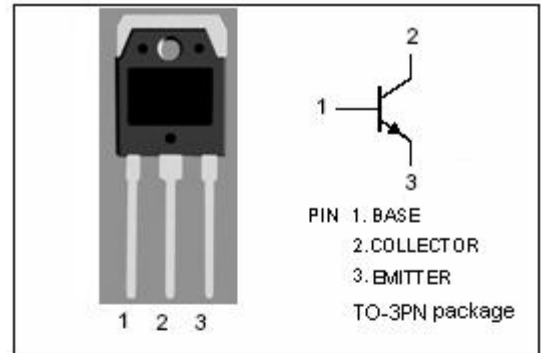
- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 800V(\text{Min})$
- Fast Switching Speed
- Wide Area of Safe Operation

**APPLICATIONS**

- Switching regulator and high voltage switching applications
- High speed DC-DC converter applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	900	V
$V_{CEO}$	Collector-Emitter Voltage	800	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current-Continuous	1.5	A
$I_{CM}$	Collector Current-Peak	5	A
$I_B$	Base Current-Continuous	0.8	A
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	60	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



**ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5mA; R <sub>BE</sub> = ∞	800			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	900			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA; I <sub>C</sub> = 0	7			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.75A; I <sub>B</sub> = 0.15A			2.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 0.75A; I <sub>B</sub> = 0.15A			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 800V; I <sub>E</sub> = 0			10	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			10	μ A
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 5V	10		40	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V	8			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 10V		15		MHz
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V		30		pF

Switching times

t <sub>r</sub>	Rise Time	I <sub>C</sub> = 1A; I <sub>B1</sub> = 0.2A; I <sub>B2</sub> = -0.4A; R <sub>L</sub> = 400 Ω ; V <sub>CC</sub> = 400V			1.0	μ s
t <sub>stg</sub>	Storage Time				3.0	μ s
t <sub>f</sub>	Fall Time				0.7	μ s

◆ **h<sub>FE-1</sub> Classifications**

K	L	M
10-20	15-30	20-40